

SPECIFICATION OF LED CHIP C565-30V [Yellow Green]

1) Commodity Type and Physical Characteristics.

1. Material	InGaAlP/GaAs	
2. Electrode	Top Side P (anode) side	: Au Alloy/Au or Au Pad
	Bottom Side N (cathode) side	: Au Alloy
3. Electrode Pattern		Fig.1
4. Chip Size		Fig.2
5. Chip Thickness		Fig.2
6. Emission Area		Fig.2

2) Electro-Optical Characteristics [Ta=25°C]

Parameters	Symbol	Condition	Min.	Typ.	Max.	Unit
Forward Voltage	Vf	If=20mA		2.0	2.3	V
Reverse Current	Ir	Vr=5V			10	uA
Brightness	Iv	If=20mA		14		mcd
Power Intensity	Po	If=20mA		0.05		mW
Peak Wavelength	λ_P	If=20mA	562	565	570	nm
Spectral Radiation Bandwidth	$\Delta\lambda$	If=20mA		15		nm
RiseTime	tr	If=20mA		-		ns
FallTime	tf	If=20mA		-		ns

‡ Die shall be mounted on TO=18 gold header without resin coated.

[Unit : um]

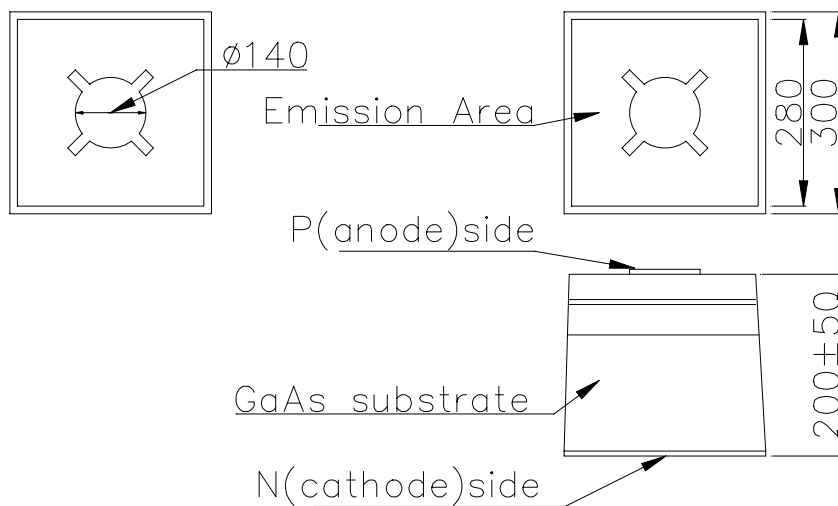


Fig.1 Electrode Pattern

Fig.2 Chip size and Emission Area